



# nEXO: The Next Generation Double-Beta Decay Experiment

**Results of nEXO detector development** 

Thomas Brunner for the nEXO collaboration TAUP2017– July 25, 2017

# Searching for $0\nu\beta\beta$ in $^{136}\text{Xe}$ with EXO



### Liquid-Xe Time Projection Chamber

- Liquid Xe at 168K
- Cryogenic electronics in LXe
- Detection of scintillation light and secondary charges
- 2D read out of secondary charges at segmented anode
- Full 3D event reconstruction:
  - 1. Energy reconstruction
  - 2. Position reconstruction
  - 3. Event Multiplicity

See talks by C. Licciardi and R. MacLellan

# Searching for $0\nu\beta\beta$ in $^{136}\text{Xe}$ with EXO



Development focuses on:

- High voltage
- Light detection
- Charge detection
- Radioassays
- (Ba-tagging)

July 25, 2017

### Liquid-Xe Time Projection Chamber

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 $T_{1/2}^{0v} > 10^{25}$  years !!  $\rightarrow$ Need:

- high target mass
- $\circ$  high exposure
- $\circ~$  low background rate
- $\circ$  good energy resolution

See talk by

Chris Chambers

## Advantages of nEXO

Build on the experience gained and the success of EXO-200 using well established techniques

- 1. Energy measurement
- 2. Event multiplicity (γ's Compton scatter depositing energy in more than one site in large detectors).
- 3. Depth in the detector (or distance from the walls) is (for large monolithic detectors) a powerful parameter for discriminating between signal and (external) backgrounds.
- α discrimination (from e<sup>-</sup> / γ), possible in many detectors.

Take full advantage of monolithic detector!

Phased approach:

1. EXO-200: 200kg liquid-Xe TPC



2. nEXO: 5-ton liquid Xe TPC with Ba tagging option (SNO lab cryopit)



### The nEXO TPC

Long, single drift

- HV
- Xe purity (low outgassing)

Novel charge tiles

- very low noise
- modularity
- self-supporting

#### SiPMs on the barrel

- optically open, reflective field cage
- no HV required
- Robust
- larger gain
- large scale production

In-Xe electronics

radioactivity



### Photon sensors



### Analog SiPMs - baseline solution for nEXO

20µm

(1000

- High gain (low noise)
- Large manufacturing capabilities ( > 4 m<sup>2</sup>)
- But efficiency and radioactivity need work

1.3x1.3 mm<sup>2</sup> T2K Multi-Pixel Photon counter Pictures courtesy of Kyoto University



### **Requirements:**

- Efficiency at 175nm > 15%
- Correlated avalanche rate < 20%
- Dark noise rate < 50Hz/mm<sup>2</sup>
- Low radioactivity

### SiPM Photodetector

At least one type of 6 x 6 mm<sup>2</sup> VUV devices now match our desired properties, with a bias requirement ~30V (as opposed to the 1500V of EXO-200 APDs)



FBK standard field SiPM: Th = 0.44+/-0.05 ppt, U = 0.99+/-0.02 ppt

### SiPM Photodetector

- Hamamatsu produces devices with QE>15% @ 175nm but encapsulation is too radioactive → trying to procure un-encapsulated devices
- First nEXO-specific run at FBK (Italy) provided ~10% QE [1.Ostrovskiy et al. IEEE TNS 62 (2015) 1825.]
- New FBK "RGB" devices reach 15% QE with 7.7 x 7.7mm<sup>2</sup>.



- Working closely with manufacturers to develop SiPMs to reach >15% QE at 175nm
- <sup>232</sup>Th and <sup>238</sup>U content of FBK SiPMs found to be <1 ppt</li>
- Development of integration of 1x1cm<sup>2</sup> SiPMs into 10x10cm<sup>2</sup> tiles
- First tests in liquid Xe



Hamamatsu MEG MPPC



FBK SiPM

Thomas Brunner

### 3D-integrated dSiPM for nEXO

Advantages over analog SiPM + analog electronics

- All in one chip assembly: photon come in, bits come out
- Power scales with avalanche count not with capacitance •
- Allow lower power or better timing resolution and granularity
- After-pulsing can be completely eliminated for a given time scale

#### Challenges

- Need custom SPAD array
- Large scale scaling •
- Significant R&D required





TIER 1 - SPAD **TIER 2 - Electronics** 

nEXO radio

### Charge Readout

Charge will be collected on arrays of strips fabricated onto low background dielectric wafers (low radioactivity quartz has been identified)

- Self-supporting/no tension
- Built-on electronics (on back)
- Far fewer cables
- Ultimately more reliable, lower noise, lower activity





Max metallization cover with min capacitance

- 10 x 10cm<sup>2</sup> Prototype Tile
- Metallized strips on fused silica substrate
- 60 orthogonal channels (30 x 30), 3mm strip pitch
- Strip intersections isolated with SiO<sub>2</sub> layer 11



# High Voltage R&D

### Focus of development

- Spark mitigation → stable operation up to -100 kV
- Protection of electronics and detector in case of HV breakdown
- High reflectivity at 175 nm
- Low radioactivity

### Ideas:

- High-resistivity Si field shaping rings to limit spark current
- Reflective coating of cathode and fieldshaping rings



### High Voltage R&D test setups

30I LXe Bern HV test setup now at Carleton U. with cryogenic cameras



400 cc LXe HV setup at SLAC



Max 800 kg LXe setup at LLNL to accommodate full or nearfull size parts horizontally (under development)



HV tests of ~30cm scale geometries

Test of breakdown voltage in LXe for different small size geometries

HV tests in LXe for different fullnEXO diameter size geometries

### Radioactivity studies of materials for nEXO

#### Techniques applied:

- Ge detector counting
- Neutron-activation analysis
- Inductively-Coupled Plasma Mass Spectrometry (IC PMS)



See talk by Ryan MacLellan

See poster by John Orrell

### nEXO Sensitivity & Discovery Potential



#### Methodology:

- 90% enrichment
- 1%  $\sigma$ E/E resolution
- Realistic background projections based on measurements
- EXO-200-like analysis

- nEXO is the next generation  $0\nu\beta\beta$  experiment with 5 T enriched LXe
- nEXO expands on the success of EXO-200 and improves performance via R&D efforts
- nEXO baseline R&D is well advanced

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### Backup

### nEXO Sensitivity to Neutrino Mass



- Allowed neutrino mass bands: 90% CL, Forero et al., PRD 90 (2014) Forero et al., private comm.
- Based on 10yr Sensitivity of 9.06 x 10<sup>27</sup> y

Calculation	Value	Mass (meV)		
Skyrme-QRPA	1.55	17.78	PRC.87.064302.2013	
QRPA-Tu	2.18	12.64	PRC.91.034304.2015	
RQRPA	2.54	10.85	PRC.91.024316.2015	
NREDF	4.77	5.78	PRC.91.024316.2015	
REDF	4.32	6.38	PRC.91.024316.2015	
ISM	2.32	11.88	NPA.818.139.2009	
IBM-2	3.05	9.04	PRC.91.034304.2015	